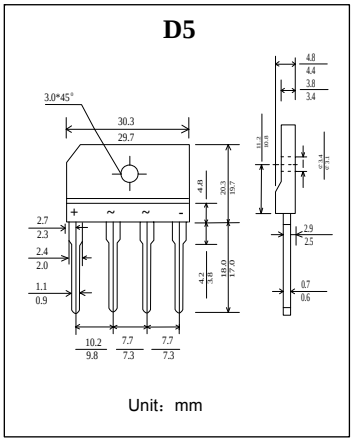
SIYU®

D20SB20.....D20SB80

塑封硅整流桥堆
反向电压 200---800V
正向电流 20 A

Single-phase Silicon Bridge Rectifier
Reverse Voltage 200 to 800V
Forward Current 20A



特征 Features

- 反向漏电流低 Low reverse leakage
- 正向浪涌承受能力较强 High forward surge capability
- 浪涌承受能力：300 A Surge overload rating: 300 Amperes peak
- 引线和管体皆符合RoHS标准 。
  Lead and body according with RoHS standard

机械数据 Mechanical Data

·封装: 塑料封装 Case: Molded Plastic
·极性: 标记模压或印于本体 Polarity: Symbols molded or marked on body
·安装位置: 任意 Mounting Position: Any
·安装扭距: 推荐值 0.5牛*米 Mounting torque：Recommend 0.5 N*m

极限值和温度特性 TA = 25℃ 除非另有规定。
Maximum Ratings & Thermal Characteristics Ratings at 25℃ ambient temperature unless otherwise specified.

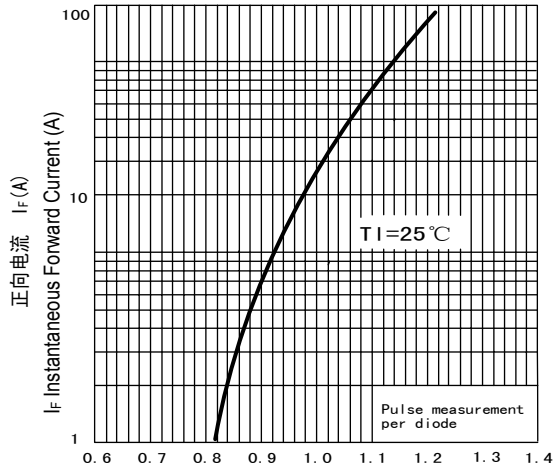
	符号 Symbols	D20SB20	D20SB40	D20SB60	D20SB80	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	V
最大均方根电压 Maximum RMS voltage	V_{RMS}	140	280	420	560	V
最大直流阻断电压 Maximum DC blocking voltage	V_{DC}	200	400	600	800	V
最大正向平均整流电流 TC =100℃ Maximum average forward rectified current	$I_{F(AV)}$	20				A
峰值正向浪涌电流 8.3ms单一正弦半波 Peak forward surge current 8.3 ms single half sine-wave	I_{FSM}	300				A
典型热阻 Typical thermal resistance	$R_{\theta JA}$	22				℃/W
工作结温和存储温度 Operating junction and storage temperature range	Tj, TSTG	-55--- +150				℃

电特性 TA = 25℃ 除非另有规定。
Electrical Characteristics Ratings at 25℃ ambient temperature unless otherwise specified.

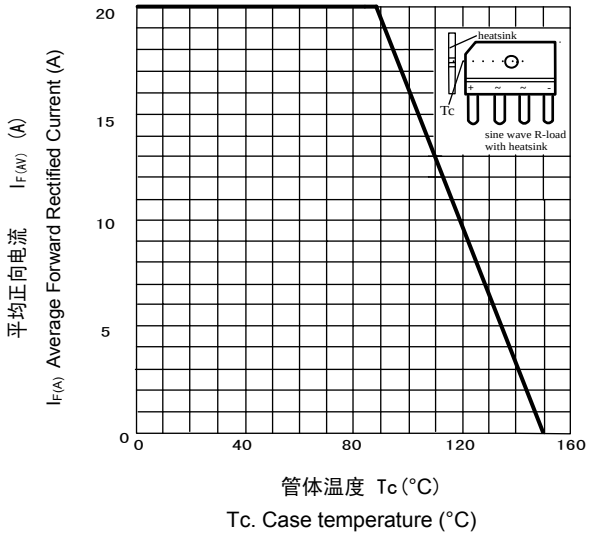
		符号 Symbols	D20SB20	D20SB40	D20SB60	D20SB80	单位 Unit
最大正向电压 Maximum forward voltage	I_F =10A	V_F	1.1				V
最大反向电流 Maximum reverse current	TA= 25℃ TA = 125℃	I_R	10 500				μA
典型结电容 V_R = 4.0V, f = 1MHz Type junction capacitance		Cj	40				pF

特性曲线 Characteristic Curves

正向特性曲线（典型值）
TYPICAL FORWARD CHARACTERISTIC



正向电流降额曲线
FORWARD CURRENT DERATING CURVE



浪涌特性曲线（最大值）
MAXIMUM NON REPETITIVE
PEAK FORWARD SURGE CURRENT

